

UFR14030C

FAST RECOVERY EPITAXIAL DIODE

ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

DESCRIPTION

The UTC **UFR14030C** utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.

FEATURES

- * Ultrafast Recovery Time
- * Soft Recovery Characteristics
- * Low Recovery Loss
- * Low Forward Voltage
- * High Surge Current Capability
- * Low Leakage Current

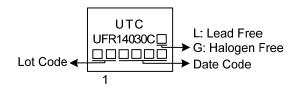
SYMBOL

ORDERING INFORMATION

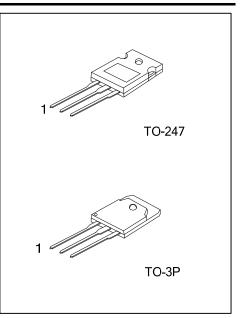
Ordering Number		Dookogo	Pin Assignment			Decking
Lead Free	Halogen Free	Package	1	2	3	Packing
UFR14030CL-T3P-T UFR14030CG-T3P-T		TO-3P	А	К	А	Tube
UFR14030CL-T47-T	UFR14030CG-T47-T	TO-247	А	К	А	Tube
Note: Pin Assignment: A: Anode K: Cathode						

UFR14030CG-T3P-T		
(1)Packing Type	(1) T: Tube	
(2)Package Type	(2) T3P: TO-3P, T47: TO-247	
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free	

MARKING







■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Maximum D.C. Reverse Voltage		V _R	300	V
Maximum Peak Repetitive Reverse Voltage		V _{RRM}	300	V
Maximum Working Peak Reverse Voltage		V _{RWM}	300	V
Maximum Average Forward Current	Per Leg		70	Α
(T _C =110°C)	Total	I _{F(AV)}	140	Α
Non-Repetitive Forward Surge Current (TJ=45°C, t=10ms, 50Hz, Sine)		I _{FSM}	300	А
Operating Temperature Range		TJ	-40 ~ +150	°C
Storage Temperature Range		T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Case	θ _{JC} 0.8		°C/W	

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	V	I _F =70A			1.3	V
Forward Voltage	V _F	I _F =70A, T _J =125°C			1.2	V
Maximum Reverse Leakage Current	I _{RM}	V _R =300V			1	μA
		V _R =300V, T _J =125°C			100	μA

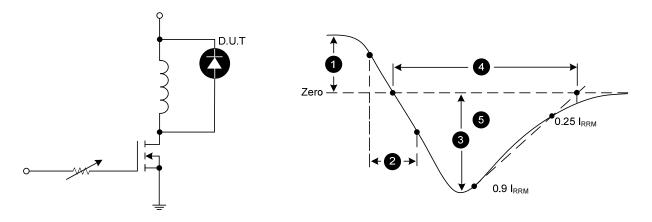
DYNAMIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Recovery Time	t _{rr}	I _F =1A, di _F /dt=-200A/µs, V _R =200V		38		ns
Reverse Recovery Time	t _{rr}	I _F =30A, di _F /dt=-100A/µs, V _R =200V		58		ns



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TEST CIRCUITS AND WAVEFORMS



Diode Reverse Recovery Test Circuit and Waveform

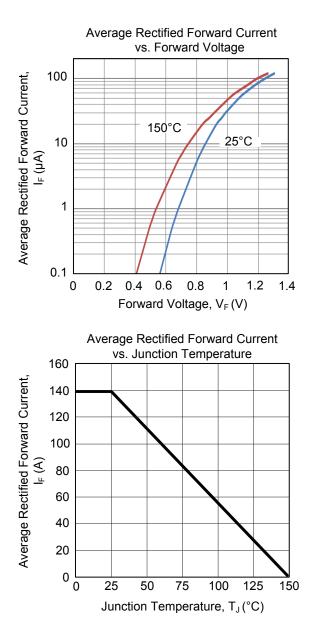
- 1. I_F Forward Conduction Current
- 2. di_F/dt Rate of Diode Current Change Through Zero Crossing.
- 3. I_{RRM} Maximum Reverse Recovery Current.
- 4. t_{rr} Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through I_{RRM} and 0.25·I_{RRM} passes through zero.
- 5. Qrr Area Under the Curve Defined by I_{RRM} and $t_{\text{rr}}.$

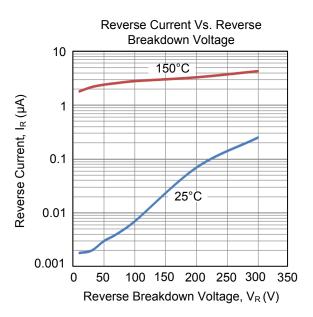


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TYPICAL CHARACTERISTICS





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